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RF2370

3V LOW NOISE AMPLIFIER

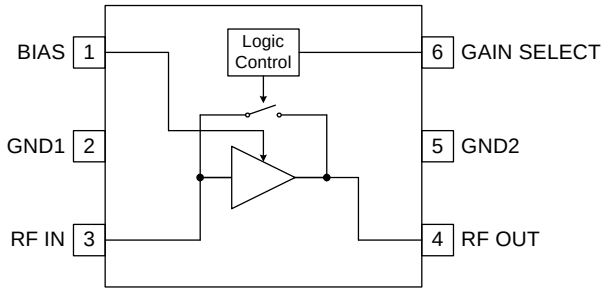
Package Style: SOT 6-Lead

Features

- Low Noise and High Intercept Point
- Adjustable Bias Current
- Power Down Control
- Low Insertion Loss Bypass Feature
- 1.8V to 5V Operation (See Note: Page 2)
- 1.5GHz to 3.8GHz Operation

Applications

- WLAN LNA with Bypass Feature
- CDMA PCS LNA with Bypass Feature
- MMDS LNA with Bypass Feature
- General Purpose Amplification
- Commercial and Consumer Systems



Functional Block Diagram

Product Description

The RF2370 is a switchable low noise amplifier with a very high dynamic range designed for digital cellular and WLAN applications. The device functions as an outstanding front end low noise amplifier. The bias current may be set externally. The IC is featured in a standard SOT 6-lead plastic package.

Ordering Information

RF2370	3V Low Noise Amplifier
RF2370PCK-410	Fully assembled evaluation board tuned for 1900 to 4000 MHz and 5 piece loose samples

Optimum Technology Matching® Applied

☑ GaAs HBT	☐ SiGe BiCMOS	☐ GaAs pHEMT	☐ GaN HEMT
☐ GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	
☐ InGaP HBT	☐ SiGe HBT	☐ Si BJT	

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Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	-0.5 to +6.0	V_{DC}
Input RF Level	+5 (see note)	dBm
Current Drain, I_{CC}	32	mA
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C

NOTE: Exceeding any one or a combination of the above maximum rating limits may cause permanent damage. Input RF transients to +15dBm will not harm the device. For sustained operation at inputs ≥+5dBm, a small dropping resistor is recommended in series with the V_{CC} in order to limit the current due to self-biasing to <32mA.

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Operating Range					T_{AMB}=+25°C, V_{CC}=3.0V
Frequency Range	900		4000	MHz	
WiBRO/WLAN/WiMAX Low Noise Amplifier					
Frequency	2300		2700	MHz	
HIGH GAIN MODE					Gain Select<0.8V, V_{BIAS}=3V, T=+25°C
Gain	12.0	14.0		dB	
Noise Figure		1.3	1.5	dB	
Input IP3		+8		dBm	IIP3 will improve if ICC is raised above 7mA.
Output VSWR		1.7:1	2:1		
Current Drain		7		mA	Current Drain=I_{CC}+I_{REF}
BYPASS MODE					Gain Select>1.8V, V_{BIAS}=0V
Gain	-4.0	-3.0	-2.0	dB	Note: Bypass mode insertion loss will degrade gradually as V_{CC} goes below 2.7V.
Input IP3	+18.0	+20.0		dBm	
Output VSWR		1.6:1			
Current Drain		2.9	3.0	mA	Current Drain=I_{CC}+I_{REF}
WiMAX Low Noise Amplifier					
Frequency	3100	3500	3800	MHz	
Gain		11		dB	Gain Select<0.8V, V_{BIAS}=3V
Noise Figure		1.6		dB	
Input IP3	+14			dBm	
BYPASS MODE (Low Gain)					Gain Select>1.8V, V_{BIAS}=0V
Gain		-4		dBm	
Input IP3	+18			dBm	
GPS Low Noise Amplifier					
Frequency	1500	1575	1600	MHz	
Gain		17		dB	Gain Select<0.8V, V_{BIAS}=3V
Noise Figure		1.2		dB	
Input IP3		+6		dBm	

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Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
BYPASS MODE (Low Gain)					Gain Select>1.8V, V_{BIAS}=0V
Gain	-4	-3		dBm	
Input IP3	+20			dBm	
Power Supply					
Voltage (V_{CC})		3		V	
V_{SELECT} Low			0.8	V	High Gain mode. Select<0.8V, V_{BIAS}=3V
V_{SELECT} High	1.8			V	Low Gain mode. Select>1.8V, V_{BIAS}=0V
Power Down	0		10	µA	Gain Select<0.8V, V_{BIAS}=0V, V_{CC}=3.0V

Bias note: Due to the presence of ESD protection circuitry on the RF2370, the maximum allowable collector bias voltage (pin 4) is 4.0V. Higher supply voltages such as 5V are permissible if a series resistor is used to drop V_{CC} to ≤4.0V for a given I_{CC}.

Bias note 2: In bypass mode, V_{REF} is essentially a "don't care" condition. Pulling V_{REF} low when in bypass mode does conserve the small 1mA to 2mA supplied by V_{REF}.

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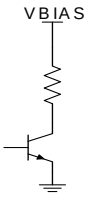
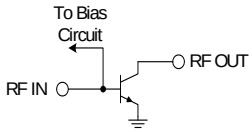
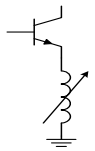
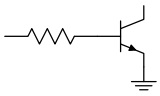
Pin	Function	Description	Interface Schematic
1	BIAS	For low noise amplifier applications, this pin is used to control the bias current. An external resistor can be used to set the bias current for any V_{BIAS} voltage.	
2	GND1	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
3	RF IN	RF input pin. This part is designed such that 50Ω is the optimal source impedance for best noise figure. Best noise figure is achieved with only a series capacitor on the input.	
4	RF OUT	Amplifier output pin. This pin is an open-collector output. It must be biased to V_{CC} through a choke or matching inductor. This pin is matched to 50Ω with a shunt L, series L topology enhances to stability of the device by reducing the high frequency gain above 6GHz.	
5	GND2	See GND1.	
6	GAIN SELECT	This pin selects high gain and bypass modes. Gain Select≤0.8V, high gain. Gain Select≥1.8V, low gain. A series resistor of 100Ω is required on this pin to enhance stability.	

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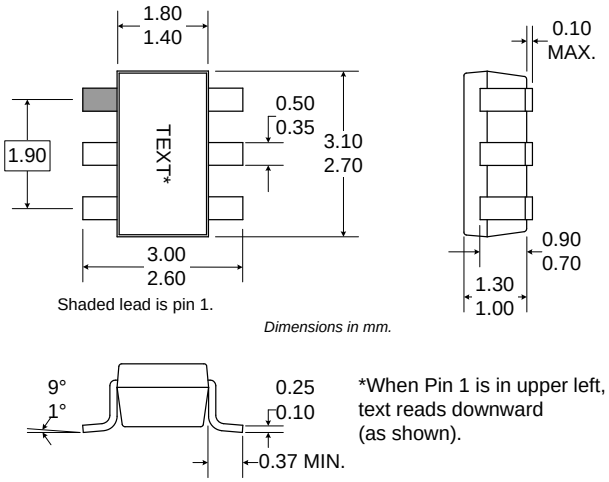
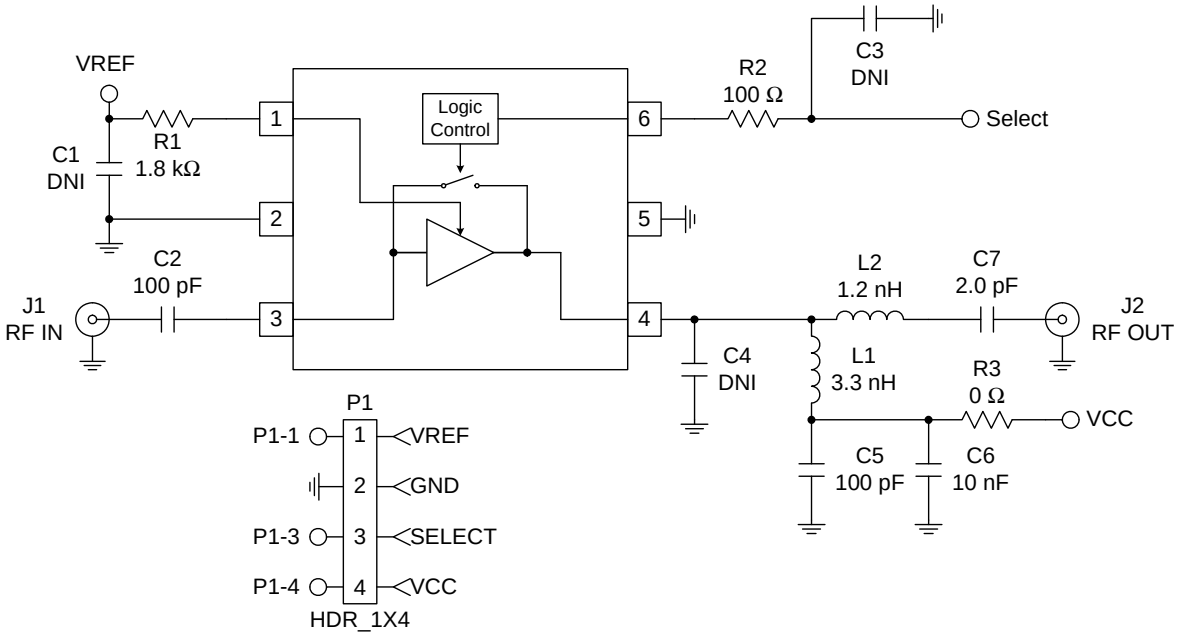
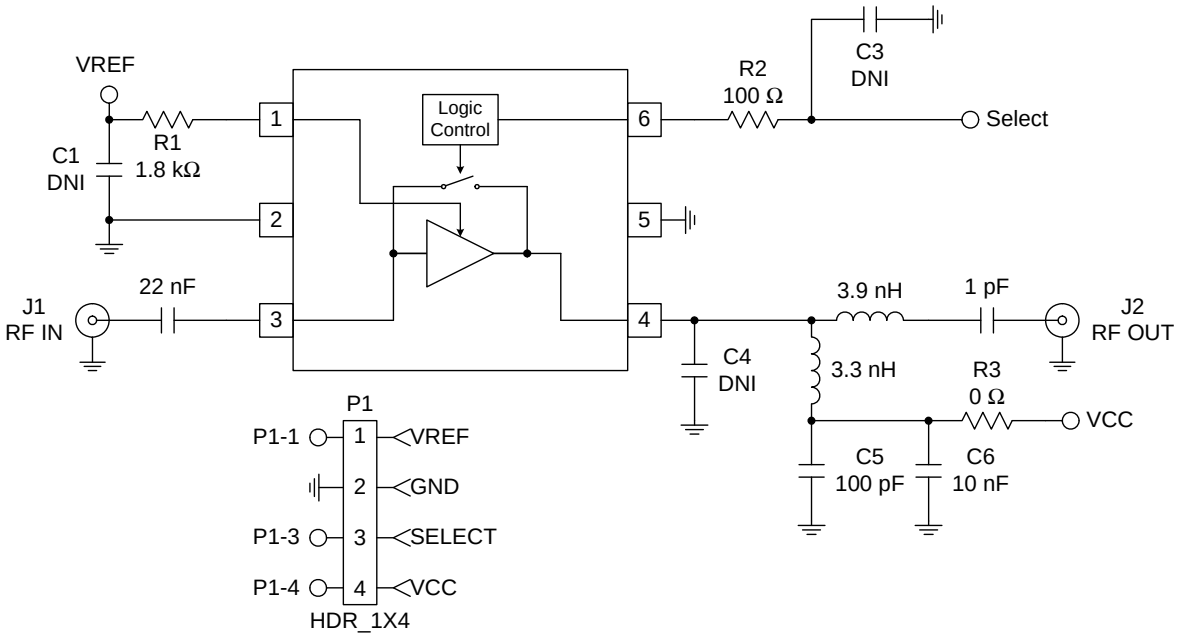
Package Drawing



Evaluation Board Schematic
WiBRO/WLAN/WiMAX Schematic (2.3GHz to 2.7GHz)



GPS Schematic
(1.5GHz to 1.6GHz)



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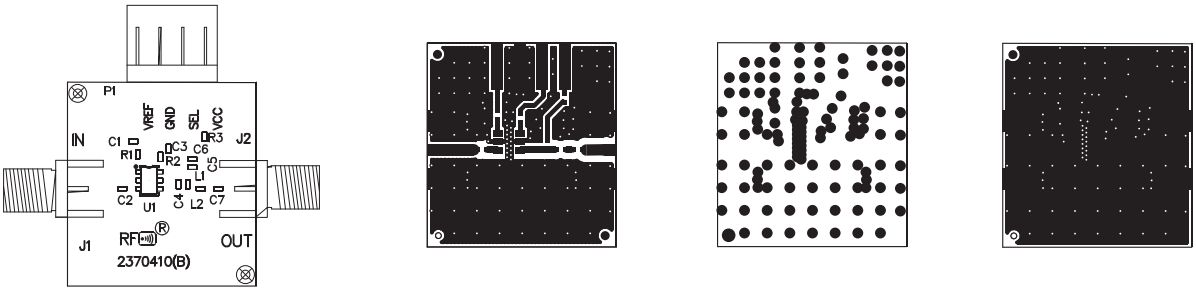
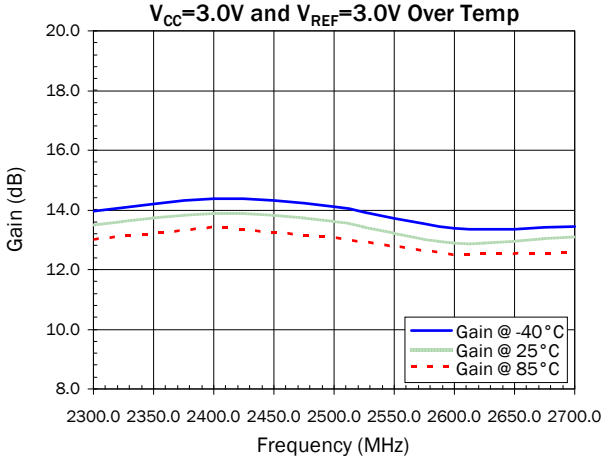
Evaluation Board Layout
Board Size 0.835” x 0.900”
Board Thickness 0.032”, Board Material FR-4

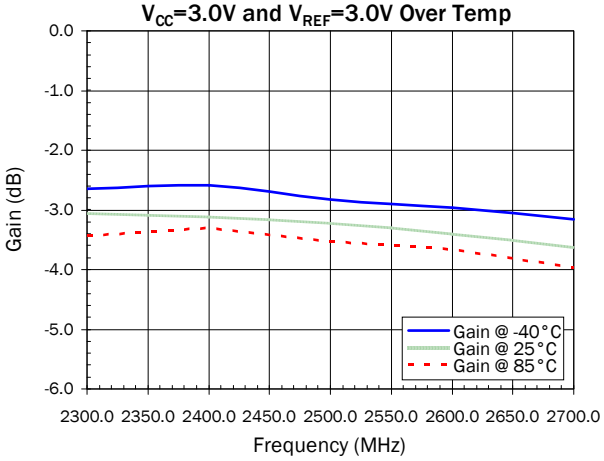


WiBRO/WLAN/WiMAX DATA

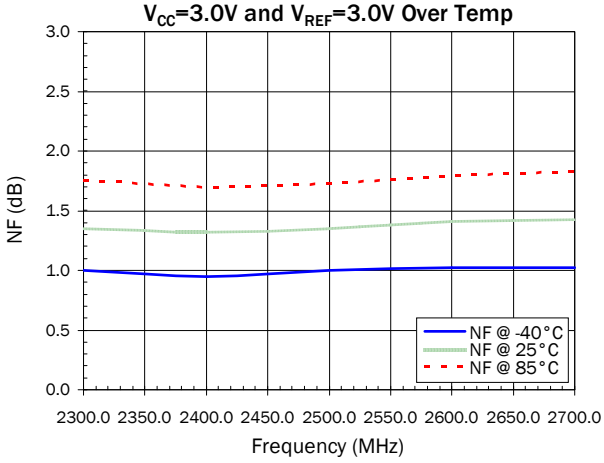
Gain @ WLAN Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



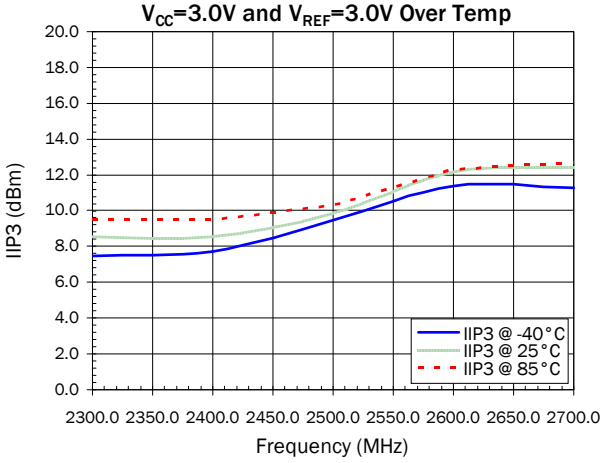
Gain @ WLAN Band in Bypass Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



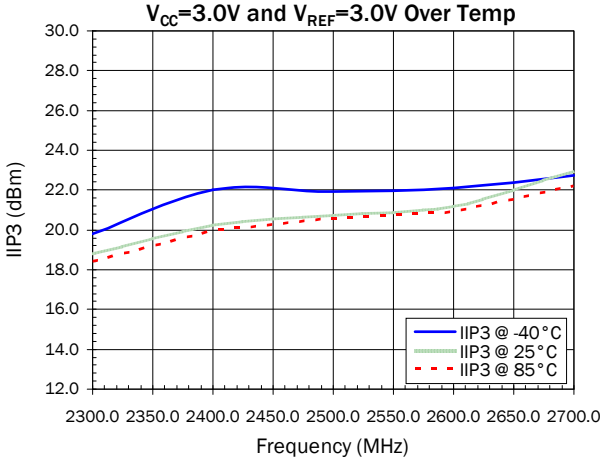
Noise Figure @ WLAN Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



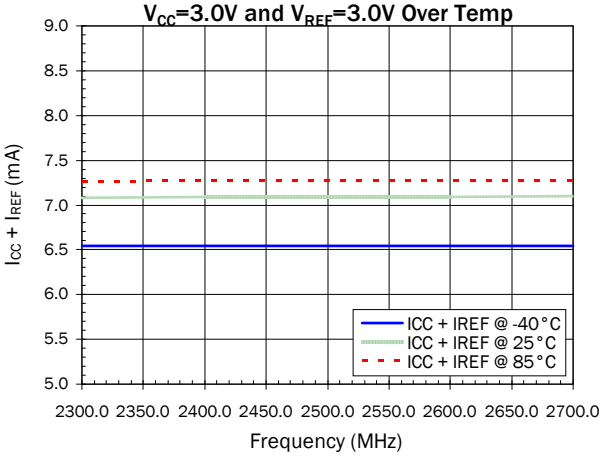
IIP3 @ WLAN Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



IIP3 @ WLAN Band in Bypass Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



I_{CC} + I_{REF} @ WLAN Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



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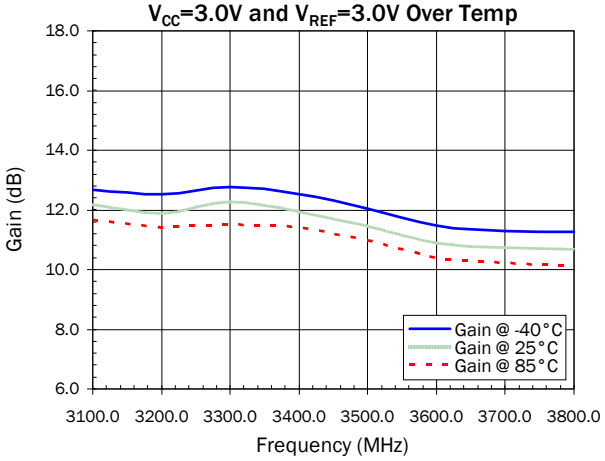
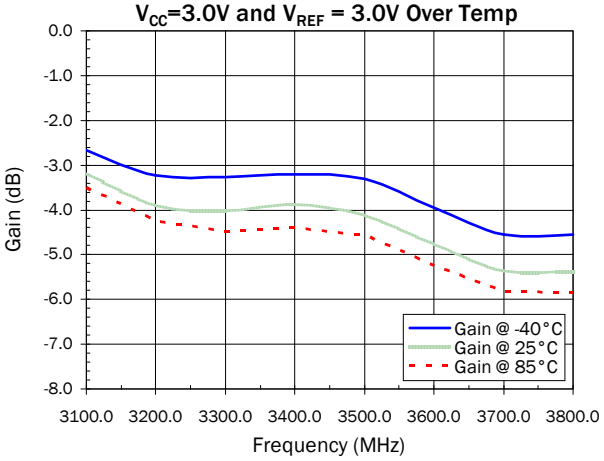
WiMAX Data

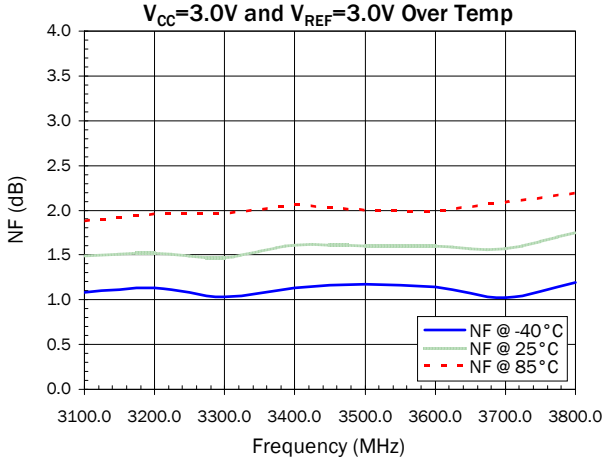
Gain @ WiMAX Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



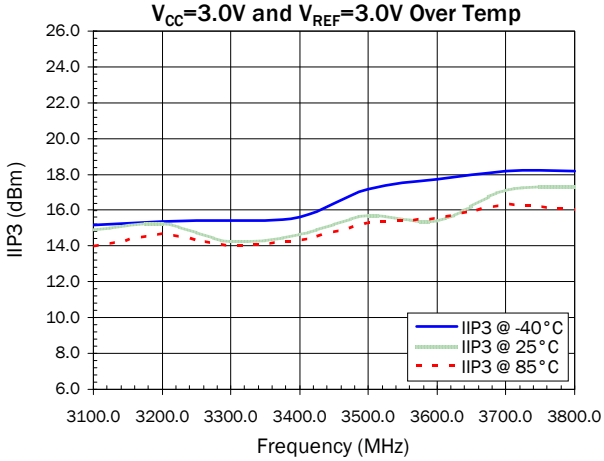
Gain @ WiMAX Band in Bypass Mode
V_{CC}=3.0V and V_{REF} = 3.0V Over Temp



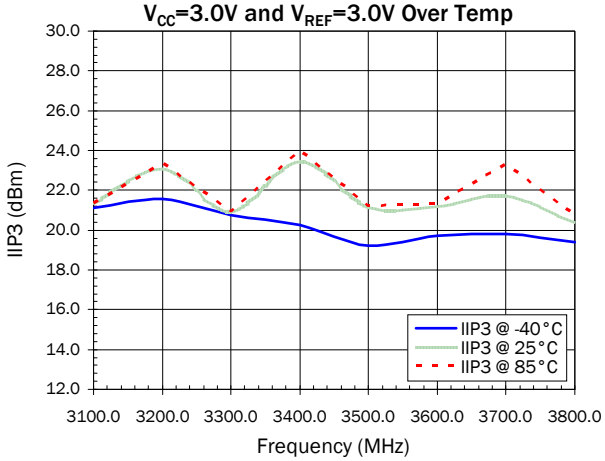
Noise Figure @ WiMAX Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



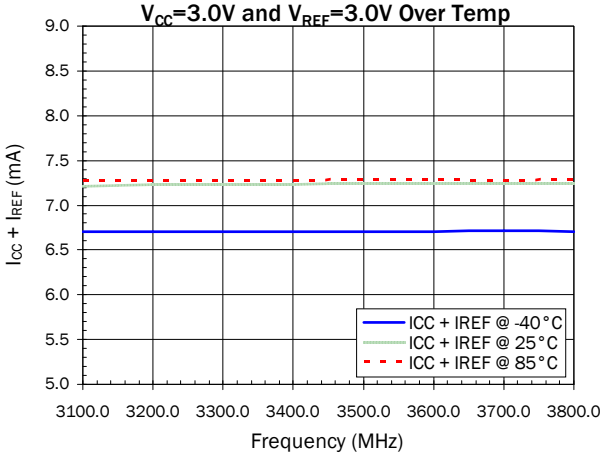
IIP3 @ WiMAX Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



IIP3 @ WiMAX Band in Bypass Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp

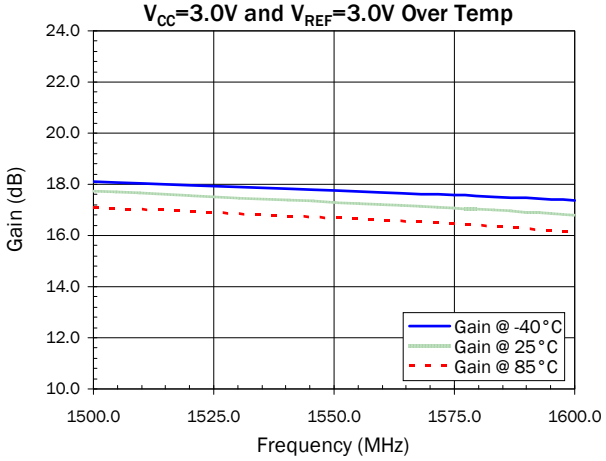


I_{CC} + I_{REF} @ WiMAX Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp

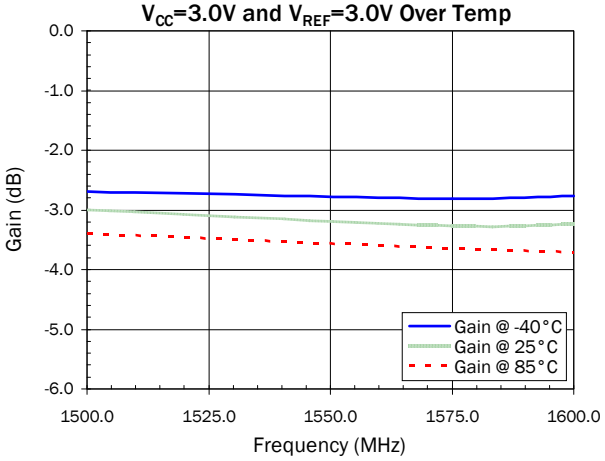


GPS Data

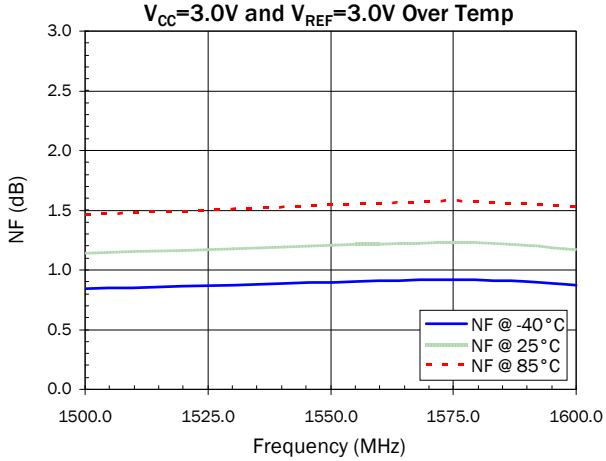
Gain @ GPS Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



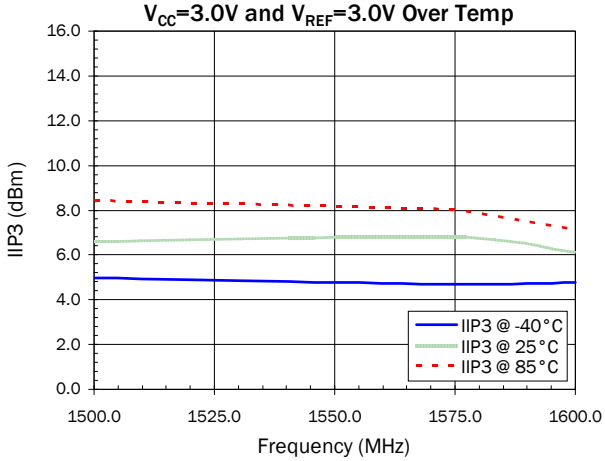
Gain @ GPS Band in Bypass Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



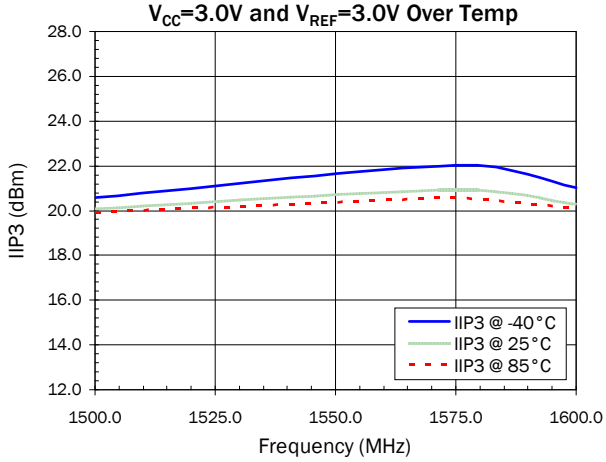
Noise Figure @ GPS Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



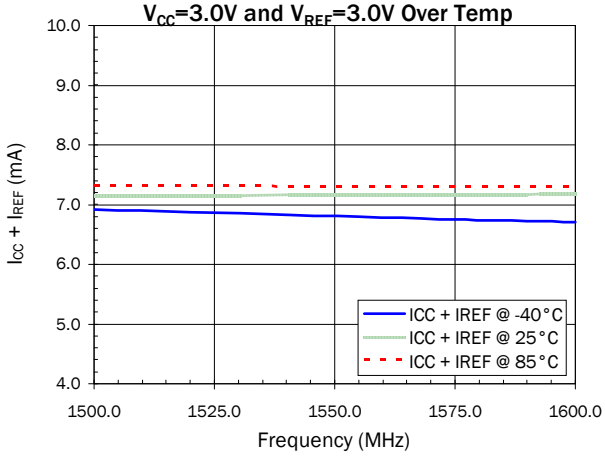
IIP3 @ GPS Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



IIP3 @ GPS Band in Bypass Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



I_{CC} + I_{REF} @ GPS Band in High Gain Mode
V_{CC}=3.0V and V_{REF}=3.0V Over Temp



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RoHS* Banned Material Content

RoHS Compliant:	Yes
Package total weight in grams (g):	0.013
Compliance Date Code:	N/A
Bill of Materials Revision:	-
Pb Free Category:	e3

Bill of Materials	Parts Per Million (PPM)					
	Pb	Cd	Hg	Cr VI	PBB	PBDE
Die	0	0	0	0	0	0
Molding Compound	0	0	0	0	0	0
Lead Frame	0	0	0	0	0	0
Die Attach Epoxy	0	0	0	0	0	0
Wire	0	0	0	0	0	0
Solder Plating	0	0	0	0	0	0

This RoHS banned material content declaration was prepared solely on information, including analytical data, provided to RFMD by its suppliers, and applies to the Bill of Materials (BOM) revision noted

* DIRECTIVE 2002/95/EC OF THE EUROPEAN PARLIAMENT AND OF THE COUNCIL of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

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